GaAs Beam Lead Schottky Diode

#### Features

- Low Series Resistance
- Low Capacitance
- High Cut-Off Frequency .
- Silicon Nitride Passivation
- **Multiple Configurations**

### **Description and Applications**

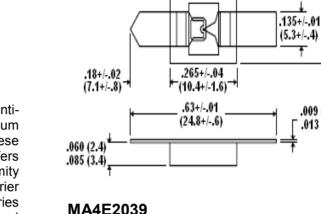
The MA4E2037 single diode, MA4E2039 antiparallel pair and MA4E2040 series tee are gallium arsenide beam lead Schottky barrier diodes. These devices are fabricated on OMCVD epitaxial wafers using a process designed for high device uniformity and extremely low parasitics. The high carrier mobility of gallium arsenide results in lower series resistance than a silicon Schottky with equivalent capacitance, resulting in lower noise figure and conversion loss. The diodes are fully passivated with silicon nitride and have an additional layer of a polymer for scratch protection. The protective coatings prevent damage to the junction and the anode air bridge during handling.

The high cut-off frequency of these diodes allows use through millimeter wave frequencies. Typical applications include single and double balanced mixers in PCN transceivers and radios, automotive radar systems and police radar detectors.

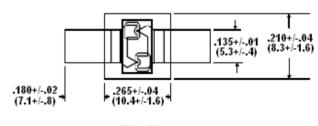
The MA4E2039 anti-parallel pair is designed for use in sub harmonically pumped mixers. Close matching of the diode characteristics in high LO suppression at the RF input.

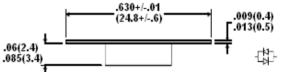
#### **Ordering Information**

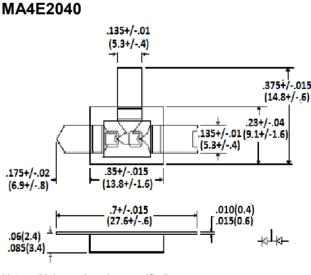
Part Number	Package
MA4E2037	Gel Pack (100 piece per)
MA4E2039	Gel Pack (100 piece per)
MA4E2040	Gel Pack (100 piece per)



MA4E2037







Notes: (Unless otherwise specified) Dimensions are in mm (mils). Views are with junction side up.

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.

1





Rev. V6

.21+/-.04

(8.3+/-1.6)

.009 (0.4)

.013 (.05)



### GaAs Beam Lead Schottky Diode

Rev. V6

### Electrical Specifications: $T_A = +25^{\circ}C$ (measured as single diodes)

Parameter & Test Conditions	Units	Min.	Тур.	Max.
MA4E2037				
Junction Capacitance @ 0 V, 1 MHz	pF	_	0.020	_
Total Capacitance @ 0 V, 1 MHz <sup>1</sup>	pF	0.030	0.045	0.060
Junction Capacitance Difference	pF	_	_	_
Series Resistance @ +10 mA <sup>2</sup>	Ω	_	4.0	7.0
Forward Voltage @ +1 mA	V	0.60	0.70	0.80
Forward Voltage Difference @ +1 mA	V	_	_	_
Reverse Voltage Breakdown @ -10 µA	V	4.5	7.0	_
MA4E2039				
Junction Capacitance @ 0 V, 1 MHz	pF	_	0.020	_
Total Capacitance @ 0 V, 1 MHz <sup>1</sup>	pF	0.030	0.045	0.060
Junction Capacitance Difference	pF	_	0.005	0.010
Series Resistance @ +10 mA <sup>2</sup>	Ω	_	4.0	7.0
Forward Voltage @ +1 mA	V	0.60	0.70	0.80
Forward Voltage Difference @ +1 mA	V	_	0.005	0.010
Reverse Voltage Breakdown @ -10 µA	V	_	_	_
MA4E2040				-
Junction Capacitance @ 0 V, 1 MHz <sup>3</sup>	pF	_	0.020	_
Total Capacitance @ 0 V, 1 MHz <sup>1,3</sup>	pF	0.030	0.045	0.060
Junction Capacitance Difference	pF	_	0.005	0.010
Series Resistance @ +10 mA <sup>2</sup>	Ω	_	4.0	7.0
Forward Voltage @ +1 mA	V	0.60	0.70	0.80
Forward Voltage Difference @ +1 mA	V	_	0.005	0.010
Reverse Voltage Breakdown @ -10 µA	V	4.5	7.0	_
	1	1	1	1

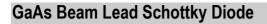
1. Total capacitance is equivalent to the sum of junction capacitance C<sub>J</sub> and parasitic capacitance C<sub>P</sub>.

2. Series resistance is determined by measuring the dynamic resistance and subtracting the junction resistance of 2.6 Ω.

3. Capacitance for the MA4E2039 and MA4E2040 is per Schottky diode.

2

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.





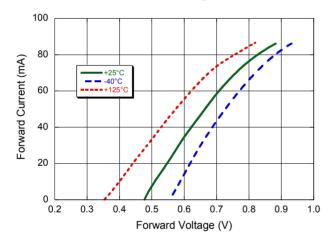
Rev. V6

### Absolute Maximum Ratings<sup>4,5</sup>

Parameter	Absolute Maximum		
Incident Power (LO & RF)	20 dBm		
Operating Temperature	-65°C to +125°C		
Storage Temperature	-65°C to +150°C		
Mounting Temperature	+235°C for 10 seconds		

4. Exceeding any one or combination of these limits may cause permanent damage to this device.

 MACOM does not recommend sustained operation near these survivability limits.



#### Forward Current vs. Temperature

#### Static Sensitivity

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these HBM Class 0 devices.

#### Handling Procedures

The protective polymer coating on the active areas of these die provides scratch protection, particularly for the metal air bridge which contacts the anode. Beam lead devices must, however, be handled with care since the leads may be easily distorted or broken by the normal pressures exerted when handled by tweezers. A vacuum pencil with a #27 tip is recommended for picking and placing.

#### **Mounting Techniques**

These devices are designed to be inserted onto hard or soft substrates. Recommended methods of attachment include thermo-compression bonding, parallel-gap welding, solder reflow and conductive epoxy. See application note M541:

*"Bonding and Handling Procedures for Chip Diode Devices"* for detailed instructions.

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.

GaAs Beam Lead Schottky Diode



Rev. V6

MACOM Technology Solutions Inc. All rights reserved.

Information in this document is provided in connection with MACOM Technology Solutions Inc ("MACOM") products. These materials are provided by MACOM as a service to its customers and may be used for informational purposes only. Except as provided in MACOM's Terms and Conditions of Sale for such products or in any separate agreement related to this document, MACOM assumes no liability whatsoever. MACOM assumes no responsibility for errors or omissions in these materials. MACOM may make changes to specifications and product descriptions at any time, without notice. MACOM makes no commitment to update the information and shall have no responsibility whatsoever for conflicts or incompatibilities arising from future changes to its specifications and product descriptions. No license, express or implied, by estoppels or otherwise, to any intellectual property rights is granted by this document.

THESE MATERIALS ARE PROVIDED "AS IS" WITHOUT WARRANTY OF ANY KIND, EITHER EXPRESS OR IMPLIED, RELATING TO SALE AND/OR USE OF MACOM PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, CONSEQUENTIAL OR INCIDENTAL DAMAGES, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT. MACOM FURTHER DOES NOT WARRANT THE ACCURACY OR COMPLETENESS OF THE INFORMATION, TEXT, GRAPHICS OR OTHER ITEMS CONTAINED WITHIN THESE MATERIALS. MACOM SHALL NOT BE LIABLE FOR ANY SPECIAL, INDIRECT, INCIDENTAL, OR CONSEQUENTIAL DAMAGES, INCLUDING WITHOUT LIMITATION, LOST REVENUES OR LOST PROFITS, WHICH MAY RESULT FROM THE USE OF THESE MATERIALS.

MACOM products are not intended for use in medical, lifesaving or life sustaining applications. MACOM customers using or selling MACOM products for use in such applications do so at their own risk and agree to fully indemnify MACOM for any damages resulting from such improper use or sale.

<sup>4</sup> 

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by MACOM manufacturer:

Other Similar products are found below :

MA4E2039 D1FH3-5063 MBR10100CT-BP MBR1545CT MMBD301M3T5G RB160M-50TR RB551V-30 BAS16E6433HTMA1 BAT 54-02LRH E6327 NSR05F40QNXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SK310-T SK32A-LTP SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP SK33B-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573 NTE6081 SB560 PMAD1108-LF SD103ATW-TP